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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/939,253	08/24/2001	James M. Derderian	4830US (01-0106)	2189
24247	7590	11/20/2003	EXAMINER	
TRASK BRITT P.O. BOX 2550 SALT LAKE CITY, UT 84110			WILLIAMS, ALEXANDER O	
			ART UNIT	PAPER NUMBER
			2826	

DATE MAILED: 11/20/2003

Please find below and/or attached an Office communication concerning this application or proceeding.

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Office Action Summary	Application No. 09/939,253	Applicant(s) DERDERIAN, JAMES M.	
	Examiner Alexander O Williams	Art Unit 2826	

-- The MAILING DATE of this communication appears on the cover sheet with the correspondence address --

Period for Reply

A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) FROM THE MAILING DATE OF THIS COMMUNICATION.

- Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.
- If the period for reply specified above is less than thirty (30) days, a reply within the statutory minimum of thirty (30) days will be considered timely.
- If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.
- Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133).
- Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).

Status

- 1) ☒ Responsive to communication(s) filed on ____.
- 2a) ☐ This action is **FINAL**. 2b) ☒ This action is non-final.
- 3) ☐ Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under *Ex parte Quayle*, 1935 C.D. 11, 453 O.G. 213.

Disposition of Claims

- 4) ☒ Claim(s) 1-67 is/are pending in the application.
- 4a) Of the above claim(s) 1-16, 27-30, 34-36, 41 and 48-67 is/are withdrawn from consideration.
- 5) ☐ Claim(s) ____ is/are allowed.
- 6) ☒ Claim(s) 1-13, 17-26, 31-33, 37-40 and 42-44 is/are rejected.
- 7) ☐ Claim(s) ____ is/are objected to.
- 8) ☐ Claim(s) ____ are subject to restriction and/or election requirement.

Application Papers

- 9) ☐ The specification is objected to by the Examiner.
- 10) ☐ The drawing(s) filed on ____ is/are: a) ☐ accepted or b) ☐ objected to by the Examiner.
 Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).
 Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).
- 11) ☐ The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.

Priority under 35 U.S.C. §§ 119 and 120

- 12) ☐ Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).
 a) ☐ All b) ☐ Some * c) ☐ None of:
 1. ☐ Certified copies of the priority documents have been received.
 2. ☐ Certified copies of the priority documents have been received in Application No. ____.
 3. ☐ Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).
 * See the attached detailed Office action for a list of the certified copies not received.
- 13) ☐ Acknowledgment is made of a claim for domestic priority under 35 U.S.C. § 119(e) (to a provisional application) since a specific reference was included in the first sentence of the specification or in an Application Data Sheet. 37 CFR 1.78.
 a) ☐ The translation of the foreign language provisional application has been received.
- 14) ☐ Acknowledgment is made of a claim for domestic priority under 35 U.S.C. §§ 120 and/or 121 since a specific reference was included in the first sentence of the specification or in an Application Data Sheet. 37 CFR 1.78.

Attachment(s)

- | | |
|--|---|
| 1) <input type="checkbox"/> Notice of References Cited (PTO-892) | 4) <input type="checkbox"/> Interview Summary (PTO-413) Paper No(s). ____ |
| 2) <input type="checkbox"/> Notice of Draftsperson's Patent Drawing Review (PTO-948) | 5) <input type="checkbox"/> Notice of Informal Patent Application (PTO-152) |
| 3) <input checked="" type="checkbox"/> Information Disclosure Statement(s) (PTO-1449) Paper No(s) ____ | 6) <input type="checkbox"/> Other: _____ |

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Art Unit: 2826

Serial Number: 09/939253 Attorney's Docket #: 4830US(01-0106)

Filing Date: 8/24/01;

Applicant: Derderian

Examiner: Alexander Williams

Applicant's Amendment and RCE have been acknowledged. The claims being examined are claims 1 to 13, 17-26, 31 to 33, 37 to 40 and 42 to 44

This application contains claims 14 to 16, 27 to 30, 34 to 36, 41 and 48 to 67 drawn to an invention non-elected without traverse in Paper No. 11.

This application contains claims 68 to 102 drawn to an invention non-elected with traverse in Paper No. 9.

Applicant's request for reconsideration of the finality of the rejection of the last Office action is persuasive and, therefore, the finality of that action is withdrawn.

The following is a quotation of the appropriate paragraphs of 35 U.S.C. § 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless --

(e) the invention was described in a patent granted on an application for patent by another filed in the United States before the invention thereof by the applicant for patent, or on an international application by another who has fulfilled the requirements of paragraphs (1), (2), and (4) of section 371(c) of this title before the invention thereof by the applicant for patent.

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negated by the manner in which the invention was made.

Claims 1 to 11, 13, 17 to 26, 31 to 33, 37 to 40 and 42 to 44 are rejected under 35 U.S.C. § 102(e) as being anticipated by Glenn et al. (U.S. Patent # 6,472,758 B1).

For example, in claim 1, Glenn et al. (figures 3 to 10) specifically figure 6 show a semiconductor device for use in a stacked multi-chip assembly, comprising: a semiconductor die **14**; and a dielectric spacer layer **48** formed on at least a portion of a surface of said semiconductor die and protruding therefrom substantially a predetermined distance that said semiconductor die and an adjacent semiconductor die **16** of said stacked multi-chip assembly are to be spaced apart from one another, said spacer layer including voids (**in figure 6, middle portion between the two 48s**) communicating with a lateral periphery thereof.

For example, in claim 19, Glenn et al. (figures 3 to 10) specifically figure 6 show a semiconductor device assembly, comprising: a first semiconductor device **14**; a nonconfluent spacer layer **48** comprising dielectric material and being positioned on a surface of said first semiconductor device, a second semiconductor device **16** positioned over said first semiconductor device, a surface of said second semiconductor device being adhered to said nonconfluent spacer layer.

In claim 37, Glenn et al. (figures 3 to 10) specifically figure 6 show a substrate **20** upon which one of said first semiconductor device **14** and said second semiconductor device **16** is positioned.

In claim 38, Glenn et al. (figures 3 to 10) specifically figure 6 show at least one bond pad **34** of at least one of said first semiconductor device and said second semiconductor device **31** is in communication (**through 38**) with a corresponding contact area **26** of said substrate **20**.

In claim 39, Glenn et al. (figures 3 to 10) specifically figure 6 show the substrate comprising at least one of a circuit board **20**, an interposer, another semiconductor device, and leads **38**

Claim 12 is rejected under 35 U.S.C. 103(a) as being unpatentable over Glenn et al. (U.S. Patent # 6,472,758 B1) and in view of Smith, Jr. et al. (U.S. Patent # 6,049,370).

Glenn et al. show the features of the claimed invention as detailed above, but fail to explicitly show a spacer layer comprising polymer, where as the polymer comprises a photoimageable polymer. Photoimageable polymer is defined to be a photoresist polymer.

Smith, Jr. et al. is cited for showing liquid crystal light valve using internal, fixed spacers. Specifically, Smith, Jr. et al. (figures 2 to 5) specifically figure 3 discloses a variety of materials may be used to form the spacer pads 40, including an oxide, such as silica or indium tin oxide, a metal, such as chromium, aluminum, or gold, and polymers, such as polyimides or photoresist materials for the purpose of giving spacing between electrical connecting materials.

Therefore, it would have been obvious to one of ordinary skill in the art to use Smith, Jr. et al.'s photoresist polymer spacer to modify Glenn et al.'s spacers for the purpose of giving spacing between electrical connecting materials.

Claims 13 and 32 are rejected under 35 U.S.C. 103(a) as being unpatentable over Glenn et al. (U.S. Patent # 6,472,758 B1) and in view of Mueller et al. (U.S. Patent # 6,316,786 B1).

Glenn et al. show the features of the claimed invention as detailed above, but fail to explicitly show a spacer layer comprising (all types) at least one of a glass, a silicon oxide, a silicon nitride, and a silicon oxynitride.

Mueller et al. is cited for showing an organic opto-electronic devices. Specifically, Mueller et al. (figures 1A to 3c) specifically figure 1B discloses spacers 13 and 15 comprising silicon nitride, SiN.sub.x, SiO.sub.x, SiO.sub.2, Siliconoxynitride (SiON), organic compounds such as polyimides, aluminiumoxide, aluminiumnitride, or titaniumoxide, for example for the purpose of providing sufficient contact between the layers and damage between the layers are avoided.

Therefore, it would have been obvious to one of ordinary skill in the art to use Mueller et al.'s spacer to modify Glenn et al.'s spacers for the purpose of providing sufficient contact between the layers and damage between the layers are avoided.

Response

Applicant's arguments filed 7/15/03 have been fully considered, but are moot in view of the outstanding grounds of rejections detailed above. Applicant's arguments on pages 12-17 have been considered but are not found to be persuasive. Applicant statement that "Glenn lacks any express or inherit description of voids I layer 42, let alone voids that communicate with a lateral periphery of spacer layer 42" is not found to be persuasive. Because there are two different materials connect provides for the smallest level of voids between the two materials.

Field of Search	Date
U.S. Class and subclass: 257/686,685,777,778,784-787,734,737,738,723,730,773	9/9/02 2/22/03 5/8/03 8/18/03 11/17/03
Other Documentation: foreign patents and literature in 257//686,685,777,778,784- 787,734,737,738,723,730,773	9/9/02 2/22/03 5/8/03 8/18/03 11/17/03
Electronic data base(s): U.S. Patents EAST	9/9/02 2/22/03 5/8/03 8/18/03 11/17/03

Papers related to this application may be submitted to Technology Center 2800 by facsimile transmission. Papers should be faxed to Technology Center 2800 via the Technology Center 2800 Fax center located in Crystal Plaza 4-5B15. The faxing of such papers must conform with the notice published in the Official Gazette, 1096 OG 30 (November 15, 1989). The Technology Center 2800 Fax Center number is (703) 308-7722 or 24. Only Papers related to Technology Center 2800 APPLICATIONS SHOULD BE FAXED to the GROUP 2800 FAX CENTER.

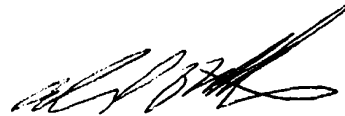
Any inquiry concerning this communication or any earlier communication from the examiner should be directed to **Examiner Alexander Williams** whose telephone number is **(703) 308-4863**.

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Any inquiry of a general nature or relating to the status of this application should be directed to the *Technology Center 2800 receptionist* whose telephone number is (703) 308-0956.

11/17/03

A handwritten signature in black ink, appearing to read 'Alexander O. Williams', with a stylized flourish at the end.

Primary Examiner
Alexander O. Williams